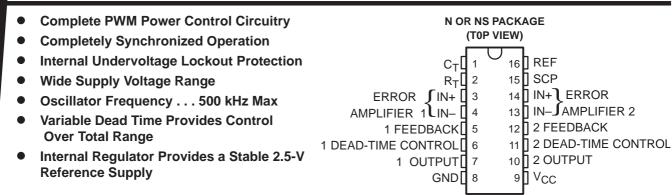
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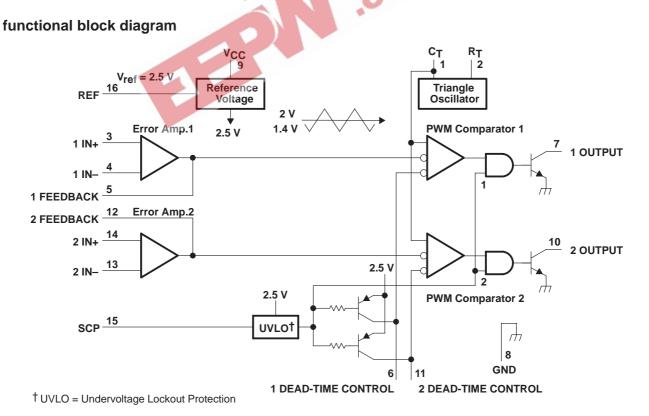


## description

The TL1453C incorporates the functions required in the construction of two pulse-width-modulation control circuits on a single monolithic chip. Designed primarily for power supply control, the TL1453C contains an on-chip 2.5-V regulator, two error amplifiers, an adjustable oscillator, two dead-time comparators, undervoltage lockout circuitry, and dual common-emitter output transistor circuits.

The uncommitted output transistors provide common-emitter output capability for each controller. The internal amplifiers exhibit a common-mode voltage range from 1.05 V to 1.45 V. The dead-time control comparator has no offset unless externally altered and may be used to provide 0% to 100% dead time. The on-chip oscillator may be operated by terminating  $R_T$  (pin 2) and  $C_T$  (pin 1), During low-VCC conditions, the undervoltage lockout control circuit feature inhibits the output until the internal circuitry is operational.

The TL1453C is characterized for operation from -20°C to 85°C.



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V <sub>CC</sub> (see Note 1)	41 V
Amplifier input voltage	20 V
Collector output voltage	51 V
Collector output current	21 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	–20°C to 85°C
Storage temperature range	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

NOTE 1: All voltage values are with respect to network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING		
N	1000 mW	8 mW/°C	520 mW
NS	725 mW	5.8 mW/°C	397 mW

## recommended operating conditions

Supply voltage, V <sub>CC</sub> Amplifier input voltage, V <sub>I</sub> Collector output voltage, V <sub>O</sub>	3.6 1.05	<b>MAX</b> 40 1.45	UNIT V
Amplifier input voltage, V <sub>I</sub>			V
	1.05	1.45	
Collector output voltage Vo			V
edifector eatput voltage, vo		50	V
Collector output current		20	mA
Current into feedback terminal		45	μΑ
Feedback resistor, R <sub>F</sub>	100		kΩ
Timing capacitor, C <sub>T</sub>	150	15000	pF
Timing resistor, R <sub>T</sub>	5.1	100	kΩ
Oscillator frequency	1	500	kHz
Operating free-air temperature, T <sub>A</sub>	-20	85	°C

# electrical characteristics over recommended operating free-air temperature range, $V_{CC} = 6 \text{ V}$ , f = 200 kHz (unless otherwise noted)

## reference section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Output voltage (pin 16)	I <sub>O</sub> = 1 mA	2.4	2.5	2.6	V
Output voltage change with temperature	$T_A = -20^{\circ}C \text{ to } 25^{\circ}C$		-0.1%	±1%	
Output voltage change with temperature	$T_A = 25^{\circ}C \text{ to } 85^{\circ}C$		-0.2%	±1%	
Input regulation	V <sub>CC</sub> = 3.6 V to 40 V		2	12.5	mV
Output regulation	$I_O = 0.1 \text{ mA to } 1 \text{ mA}$		1	7.5	mV
Short-circuit output current	V <sub>O</sub> = 0	3	10	30	mA

 $<sup>\</sup>dagger$  All typical values are at T<sub>A</sub> = 25°C.



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electrical characteristics over recommended operating free-air temperature range,  $V_{CC}$  = 6 V, f = 200 kHz (unless otherwise noted) (continued)

## undervoltage lockout section

PARAMETER	TEST CONDITIONS	MIN TYPT MAX	UNIT
Upper threshold voltage (pin 9)	$I_{Oref} = 0.1 \text{ mA},  T_A = 25^{\circ}\text{C}$	2.72	V
Lower threshold voltage (pin 9)	$I_{Oref} = 0.1 \text{ mA},  T_A = 25^{\circ}\text{C}$	2.6	V
Hysteresis (pin 9)	$I_{Oref} = 0.1 \text{ mA}, T_A = 25^{\circ}C$	80 120	mV

## oscillator section

PARAMETER	TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Frequency	$C_T = 330 \text{ pF, } R_T = 10 \text{ k}\Omega$		200		kHz
Standard deviation of frequency	V <sub>CC</sub> , T <sub>A</sub> , R <sub>T</sub> , C <sub>T</sub> values are constant		10%		
Frequency change with voltage	V <sub>CC</sub> = 3.6 V to 40 V	1%			
Frequency change with temperature	$T_A = -20$ °C to 25°C		-0.4%	±2%	
Trequency change with temperature	T <sub>A</sub> = 25°C to 85°C		-0.2%	±2%	

#### dead-time control section

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
Input bias current (pins 6 and 11)	- 3	30			1	μΑ
Januari through and suplicance of fig. 40kHz (ping C and 44)		Zero duty cycle		2.05	2.25	.,
Input threshold voltage at f = 10kHz (pins 6 and 11)	3	Maximum duty cycle	1.2	1.45		V

## error-amplifier section

PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Input offset voltage	V <sub>O</sub> (pins 5 and 12) = 1.25 V			±6	mV
Input offset current	V <sub>O</sub> (pins 5 and 12) = 1.25 V			±100	nA
Input bias current	V <sub>O</sub> (pins 5 and 12) = 1.25 V		160	500	nA
Common-mode input voltage range	V <sub>CC</sub> = 3.6 V to 40 V	1.05 to 1.45			V
Open-loop voltage amplification	R <sub>F</sub> = 200 kΩ	70	80		dB
Unity-gain bandwidth			1.5		MHz
Common-mode rejection ratio		60	80		dB
Positive output voltage swing		V <sub>ref</sub> -0.1			V
Negative output voltage swing				1	V
Output (sink) current (pins 5 and 12)	$V_{ID} = -0.1 \text{ V},  V_{O} = 1.25 \text{ V}$	0.5	1.6		mA
Output (source) current (pins 5 and 12)	$V_{ID} = 0.1 \text{ V},  V_{O} = 1.25 \text{ V}$	-45	-70		μΑ

## output section

PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Collector off-state current	$V_{CC} = 0$ , $V_{O} = 50 \text{ V}$			10	
Conector on-state current	V <sub>O</sub> = 50 V			10	μΑ
Output saturation voltage	I <sub>O</sub> = 10 mA		1.2	2	V
Short-circuit output current	VO = 6 V		90		mA

<sup>†</sup> All typical values are at  $T_A = 25^{\circ}C$ .



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electrical characteristics over recommended operating free-air temperature range,  $V_{CC} = 6 \text{ V}$ , f = 200 kHz (unless otherwise noted) (continued)

## pwm comparator section

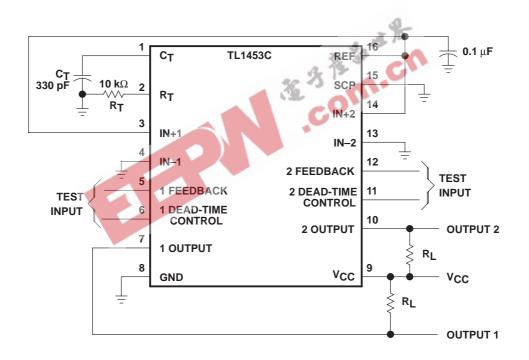
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Input threshold voltage at f = 10 kHz (pins 5 and 12)	Zero duty cycle		2.05	2.25	\/
Imput tillestiold voltage at t = 10 kmz (pills 5 and 12)	Maximum duty cycle	1.2	1.45		V
Input (sink) current (pins 5 and 12)	V <sub>I</sub> = 1.25 V	0.5	1.6		mA
Input (source) current (pins 5 and 12)	V <sub>I</sub> = 1.25 V	-45	-70		μΑ

## total device

PARAMETER	TEST CONDITIONS	MIN	TYP <sup>†</sup>	MAX	UNIT
Standby supply current	Off-state		1.3	1.8	mA
Average supply current	$R_T = 10 \text{ k}\Omega$		1.7	2.4	mA

<sup>†</sup> All typical values are at  $T_A = 25$ °C.

## test circuit

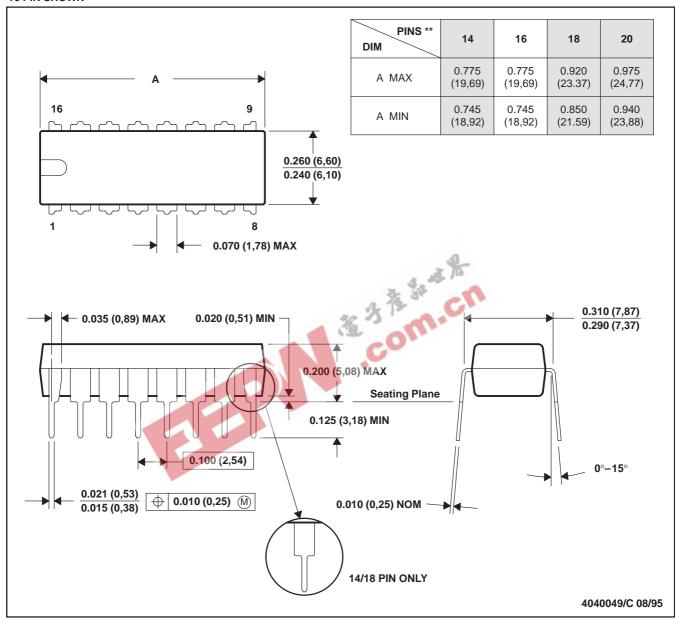


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## N (R-PDIP-T\*\*)

#### PLASTIC DUAL-IN-LINE PACKAGE

#### **16 PIN SHOWN**



NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

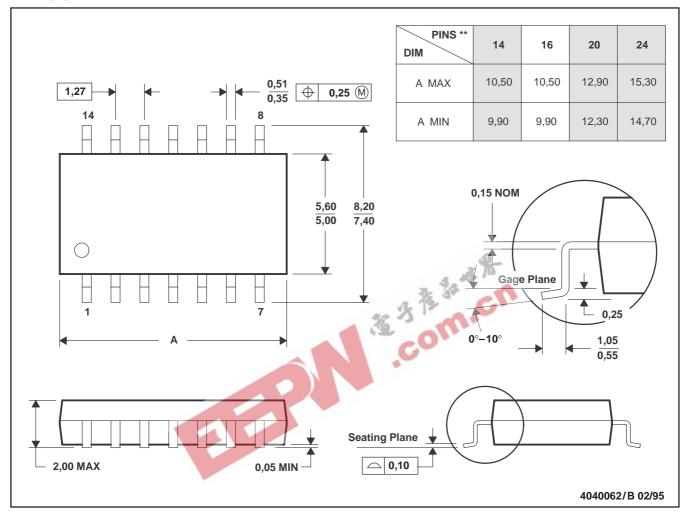
C. Falls within JEDEC MS-001 (20 pin package is shorter then MS-001.)

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## NS (R-PDSO-G\*\*)

## PLASTIC SMALL-OUTLINE PACKAGE

#### 14 PIN SHOWN



NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

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